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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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## MOS FIELD EFFECT TRANSISTOR $\mu$ PA2714GR

#### SWITCHING P-CHANNEL POWER MOS FET

#### DESCRIPTION

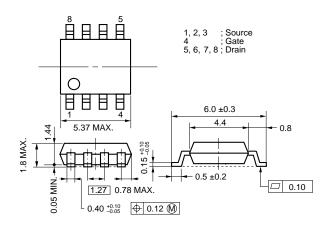
The  $\mu$ PA2714GR is P-Channel MOS Field Effect Transistor designed for power management applications of notebook computers and Li-ion battery protection circuit.

#### FEATURES

- Low on-state resistance  $R_{DS(on)1} = 20 \text{ } m\Omega \text{ } MAX. \text{ } (V_{GS} = -10 \text{ } V, \text{ } \text{I} \text{D} = -3.5 \text{ } \text{A})$   $R_{DS(on)2} = 30 \text{ } m\Omega \text{ } MAX. \text{ } (V_{GS} = -4.5 \text{ } V, \text{ } \text{I} \text{D} = -3.5 \text{ } \text{A})$  $R_{DS(on)3} = 34 \text{ } m\Omega \text{ } MAX. \text{ } (V_{GS} = -4.0 \text{ } V, \text{ } \text{I} \text{D} = -3.5 \text{ } \text{A})$
- Low Ciss: Ciss = 1370 pF TYP.
- Small and surface mount package (Power SOP8)

#### **ORDERING INFORMATION**

PART NUMBER	PACKAGE
μPA2714GR	Power SOP8



PACKAGE DRAWING (Unit: mm)

#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

Drain to Source Voltage (Vgs = 0 V)	VDSS	-30	V	
Gate to Source Voltage (VDS = 0 V)	Vgss	∓20	V	
Drain Current (DC)	D(DC)	<b>∓7</b>	А	EQUIVALENT CIRCUIT
Drain Current (pulse) <sup>Note1</sup>	D(pulse)	∓28	А	5
Total Power Dissipation Note2	P <sub>T1</sub>	2	W	Drain Q
Total Power Dissipation Note3	<b>P</b> T2	2	W	Body
Channel Temperature	Tch	150	°C	Gate Diode
Storage Temperature	Tstg	–55 to +150	°C	
Single Avalanche Current Note4	las	-7	А	
Single Avalanche Energy <sup>Note4</sup>	Eas	4.9	mJ	Source

**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

- 2. Mounted on a ceramic substrate of 1200 mm<sup>2</sup> x 2.2 mm
- 3. Mounted on a glass epoxy board (1 inch x 1 inch x 0.8 mm), PW = 10 sec
- **4.** Starting T<sub>ch</sub> = 25°C, V<sub>DD</sub> = -15 V, R<sub>G</sub> = 25  $\Omega$ , L = 100  $\mu$ H, V<sub>GS</sub> = -20  $\rightarrow$  0 V
- **Remark** Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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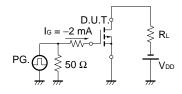
#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C, All terminals are connected.)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			-1	μA
Gate Leakage Current	lgss	$V_{GS} = \mp 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			<b>∓100</b>	nA
Gate Cut-off Voltage	VGS(off)	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -1 \text{ mA}$	-1.0		-2.5	V
Forward Transfer Admittance	yfs	$V_{DS} = -10 \text{ V}, \text{ ID} = -3.5 \text{ A}$	5	11		S
Drain to Source On-state Resistance	RDS(on)1	$V_{GS} = -10 \text{ V}, \text{ Id} = -3.5 \text{ A}$		16	20	mΩ
	RDS(on)2	$V_{GS} = -4.5 \text{ V}, \text{ Id} = -3.5 \text{ A}$		22	30	mΩ
	RDS(on)3	$V_{GS} = -4.0 \text{ V}, \text{ I}_{D} = -3.5 \text{ A}$		25	34	mΩ
Input Capacitance	Ciss	$V_{DS} = -10 V$		1370		рF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V		390		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		240		pF
Turn-on Delay Time	td(on)	$V_{DD} = -15 \text{ V}, \text{ Id} = -3.5 \text{ A}$		8		ns
Rise Time	tr	V <sub>GS</sub> = -10 V		15		ns
Turn-off Delay Time	td(off)	R <sub>G</sub> = 10 Ω		76		ns
Fall Time	tr			42		ns
Total Gate Charge	QG	$V_{DD} = -24 V$		31		nC
Gate to Source Charge	QGS	V <sub>GS</sub> = -10 V		4		nC
Gate to Drain Charge	Qgd	ID = 7 A		9		nC
Body Diode Forward Voltage	VF(S-D)	IF = 7 A, VGS = 0 V		0.82		V
Reverse Recovery Time	trr	IF = 7 A, VGS = 0 V		43		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		27		nC

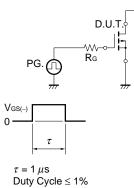
#### TEST CIRCUIT 1 AVALANCHE CAPABILITY

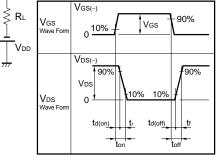
# $PG. \bigcirc Starting T_{ch}$

#### TEST CIRCUIT 3 GATE CHARGE

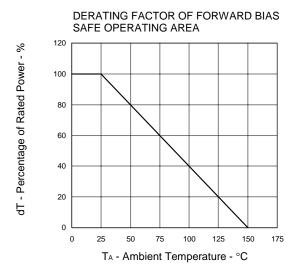


#### TEST CIRCUIT 2 SWITCHING TIME

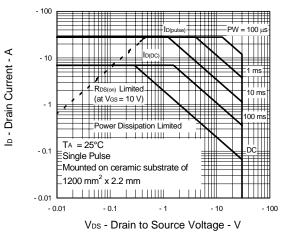


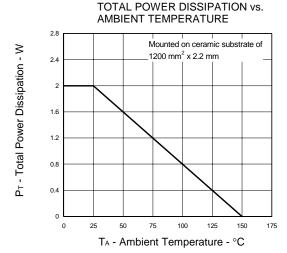


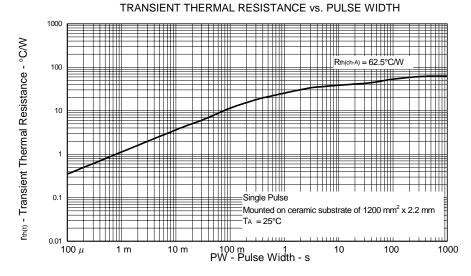
#### TYPICAL CHARACTERISTICS (TA = 25°C)



FORWARD BIAS SAFE OPERATING AREA







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- 3

- 2.5

- 2

- 1.5

- 1

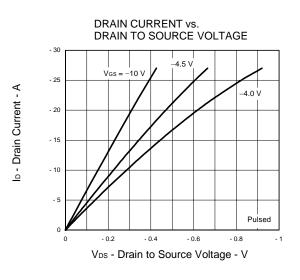
- 0.5

0

-50

0

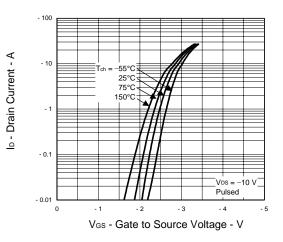
V<sub>GS(off)</sub> - Gate Cut-off Voltage - V



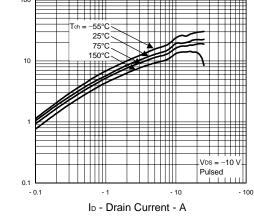
GATE CUT-OFF VOLTAGE vs.

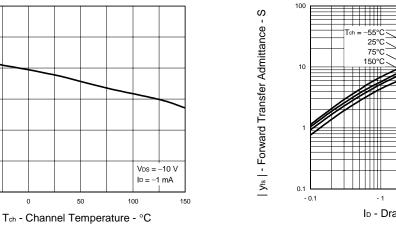
CHANNEL TEMPERATURE

FORWARD TRANSFER CHARACTERISTICS



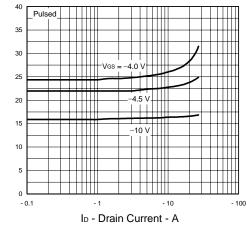
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



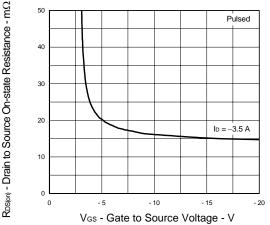


DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

50



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



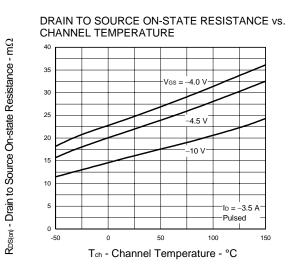
 $R^{DS(on)}$  - Drain to Source On-state Resistance -  $m\Omega$ 

1000

100

10

- 0.1



SWITCHING CHARACTERISTICS

ID - Drain Current - A

- 10

-VDD = -15 V

Vgs = -10 V

Rg = 10 Ω

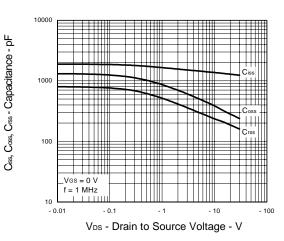
td(off

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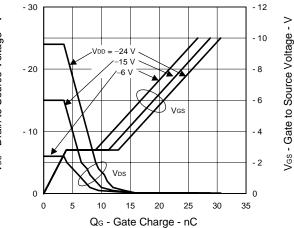
td(or

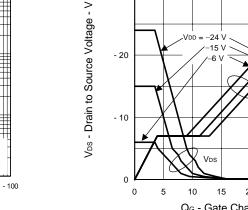
- 1

CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



DYNAMIC INPUT/OUTPUT CHARACTERISTICS

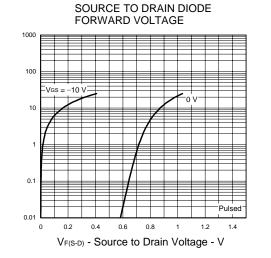


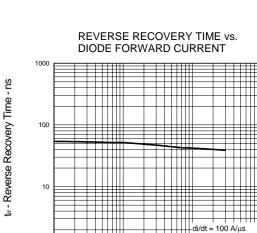




td(on), tr, td(off), tr - Switching Time - ns

IF - Diode Forward Current - A





10 1 IF - Diode Forward Current - A

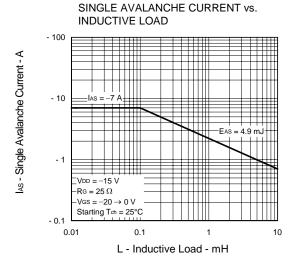
 $V_{GS} = 0 V$ 

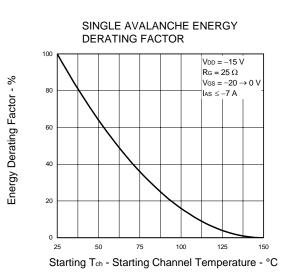
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